

Notice of References Cited	Application/Control No. 10/663,020		Applicant(s)/Patent Under Reexamination CHASE ET AL.	
	Examiner Magid Y. Dimyan		Art Unit 2825	Page 1 of 1

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*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
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*	B	US-6,650,768 B1	11-2003	Evans et al.	382/145
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NON-PATENT DOCUMENTS

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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.